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Email & Skype: info@chipsmall.com Web: www.chipsmall.com

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## FFH30US30DN

## 30A, 300V Stealth™ Diode

### **General Description**

The FFH30US30DN is a Stealth<sup>TM</sup> diode optimized for low loss performance in output rectification. The Stealth<sup>TM</sup> family exhibits low reverse recovery current ( $I_{RM(REC)}$ ), low  $V_F$  and soft recovery under typical operating conditions.

This device is intended for use as an output rectification diode in Telecom power supplies and other power switching applications. Lower  $V_F$  and  $I_{\text{RM}(\text{REC})}$  reduces diode losses.

Formerly developmental type TA49449.

#### **Features**

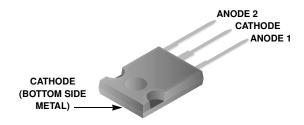
•	Soft Recovery $\dots t_b/t_a > 0.45$
•	Fast Recovery $t_{rr}$ < 50ns
•	High Operating Temperature 175°C
•	Reverse Voltage
•	Avalanche Energy Rating

### **Applications**

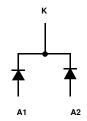
- Switch Mode Power Supplies
- · Power Factor Correction
- · Uninterruptable Power Supplies
- · Motor Drives
- Welders

### **Package**

### **JEDEC STYLE 3 LEAD TO-247**



# **Symbol**



# **Device Maximum Ratings (per leg)** $T_C = 25$ °C unless otherwise noted

etitive Peak Reverse Voltage king Peak Reverse Voltage Blocking Voltage rage Rectified Forward Current (T <sub>C</sub> = 160°C) I Device Current (Both Legs)	300 300 300 30	V V V A
Blocking Voltage rage Rectified Forward Current (T <sub>C</sub> = 160°C)	300	V
rage Rectified Forward Current (T <sub>C</sub> = 160°C)		<u> </u>
	30	۸
· · · · · · · · · · · · · · · · · · ·	60	A
etitive Peak Surge Current (20kHz Square Wave)	70	Α
repetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	325	Α
er Dissipation	230	W
anche Energy (1A, 40mH)	20	mJ
rating and Storage Temperature Range	-55 to 175	°C
imum Temperature for Soldering		
eads at 0.063in (1.6mm) from Case for 10s	300 260	°C
i	repetitive Peak Surge Current (20kHz Square Wave) repetitive Peak Surge Current (Halfwave 1 Phase 60Hz) rer Dissipation ranche Energy (1A, 40mH) rating and Storage Temperature Range rmum Temperature for Soldering	retitive Peak Surge Current (20kHz Square Wave) 70 repetitive Peak Surge Current (Halfwave 1 Phase 60Hz) 325 rer Dissipation 230 ranche Energy (1A, 40mH) 20 rating and Storage Temperature Range -55 to 175 mum Temperature for Soldering rads at 0.063in (1.6mm) from Case for 10s 325 325 326 327 328 329 329 320 320 320 321 322 323 324 325 326 327 328 329 329 320 320 320 320

CAUTION: Stresses above those listed in "Device Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Package Marking and Ordering In  Device Marking Device			Package	Tape Width			Quantity	
30US30DN		FFH30US30DN	TO-247	· ·			30	
Electric	cal Char	acteristics (per le	<b>g)</b> T <sub>C</sub> = 25°C unle	ess otherwise noted				
Symbol Parameter		Test 0	Test Conditions		Тур	Max	Units	
Off State	Charact	eristics						
I <sub>R</sub>	Instantane	ous Reverse Current	V <sub>R</sub> = 300V	V <sub>R</sub> = 300V T <sub>C</sub> = 25°C		-	100	μΑ
				T <sub>C</sub> = 125°C	-	-	1	mA
On State	Charact	eristics	•			•		•
V <sub>F</sub>		ous Forward Voltage	I <sub>F</sub> = 30A	T <sub>C</sub> = 25°C	-	0.93	1.0	V
'		<b>-</b>		$T_{\rm C} = 125^{\circ}{\rm C}$	-	0.8	0.87	V
CJ	Charact Junction C	apacitance	V <sub>R</sub> = 10V, I <sub>F</sub> = 0	A	-	410	-	рF
<u> </u>	g Charac	•	• R = 10 •, • F = 0			110		P1
t <sub>rr</sub>		ecovery Time	I_ = 1A dI_/dt =	100A/μs, V <sub>R</sub> = 15V	_	29	50	ns
۲r	Theverse riccovery rime		$I_F = 30A$ , $dI_F/dt = 100A/\mu s$ , $V_B = 15V$		-	32	55	ns
t <sub>rr</sub>	Reverse R	ecovery Time	I <sub>F</sub> = 30A,		-	46	-	ns
I <sub>RM(REC)</sub>	<del>   </del>		$dI_F/dt = 200A/\mu s$ ,		-	5.3	-	Α
Q <sub>RR</sub>	Reverse R	ecovered Charge	ery Time $I_F = 30A$ , $(t_b/t_a)$ $dI_F/dt = 200A/\mu s$ , $V_R = 195V$ , $T_0 = 125^{\circ}C$		-	140	-	nC
t <sub>rr</sub>	Reverse R	ecovery Time			-	77	-	ns
S	Softness F	actor (t <sub>b</sub> /t <sub>a</sub> )			-	0.45	-	-
I <sub>RM(REC)</sub>	Maximum	Reverse Recovery Current			-	9	-	Α
Q <sub>RR</sub>	Reverse R	ecovered Charge			-	400	-	nC
~nn	Reverse R	ecovery Time	I <sub>F</sub> = 30A,		-	54	-	ns
t <sub>rr</sub>	TICVOISC II		dI <sub>F</sub> /dt = 1000A/μs,		_	0.49	-	-
		actor (t <sub>b</sub> /t <sub>a</sub> )		13,				
t <sub>rr</sub>	Softness F	actor (t <sub>b</sub> /t <sub>a</sub> ) Reverse Recovery Current	V <sub>R</sub> =195V,	15,	-	32	-	Α
t <sub>rr</sub> S	Softness F Maximum	· 5 u					-	A nC
t <sub>rr</sub> S I <sub>RM(REC)</sub> Q <sub>RR</sub>	Softness F Maximum	Reverse Recovery Current ecovered Charge	V <sub>R</sub> =195V,	45,	-	32		
t <sub>rr</sub> S I <sub>RM(REC)</sub> Q <sub>RR</sub>	Softness F Maximum Reverse R	Reverse Recovery Current ecovered Charge	V <sub>R</sub> =195V,	45,	-	32		

# Typical Performance Curves (per leg)

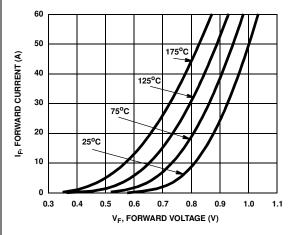


Figure 1. Forward Current vs Forward Voltage

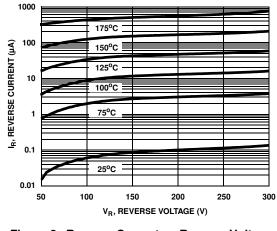


Figure 2. Reverse Current vs Reverse Voltage

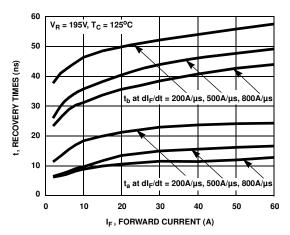


Figure 3.  $t_a$  and  $t_b$  Curves vs Forward Current

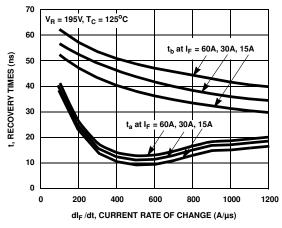


Figure 4. t<sub>a</sub> and t<sub>b</sub> Curves vs dl<sub>F</sub>/dt

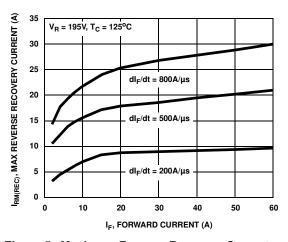


Figure 5. Maximum Reverse Recovery Current vs Forward Current

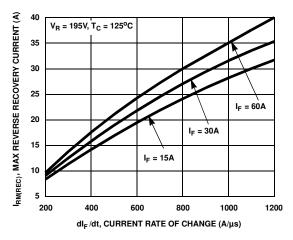


Figure 6. Maximum Reverse Recovery Current vs  $dI_F/dt$ 

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## Typical Performance Curves (per leg) (Continued)

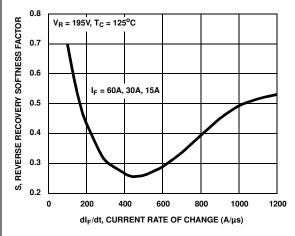


Figure 7. Reverse Recovery Softness Factor vs  $dI_F/dt$ 

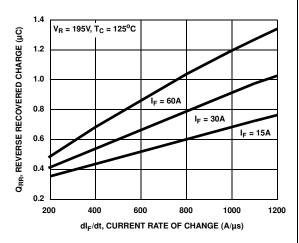


Figure 8. Reverse Recovery Charge vs dl<sub>F</sub>/dt

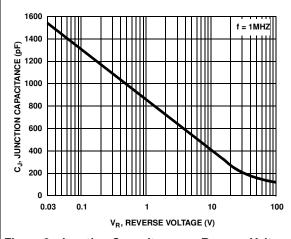


Figure 9. Junction Capacitance vs Reverse Voltage

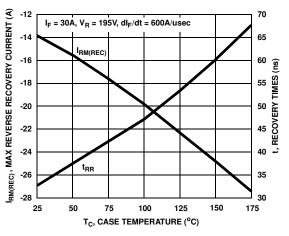


Figure 10. Maximum Reverse Recovery Current and t<sub>rr</sub> vs Case Temperature

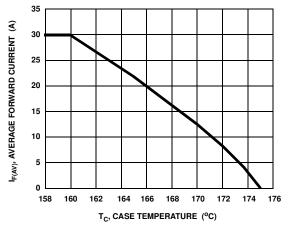


Figure 11. DC CURRENT DERATING CURVE

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# Typical Performance Curves (per leg) (Continued)

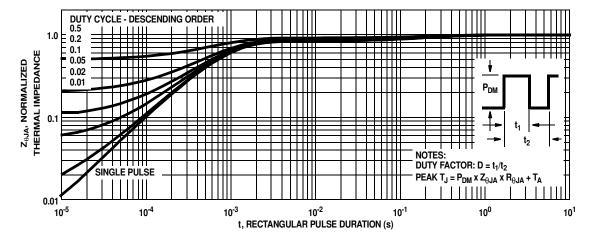
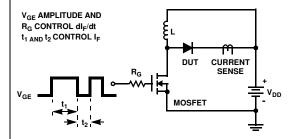


Figure 12. Normalized Maximum Transient Thermal Impedance

### Test Circuit and Waveforms



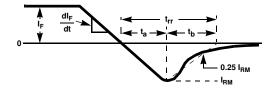
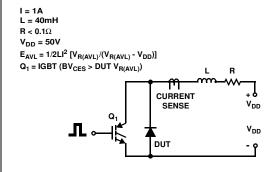


Figure 13. t<sub>rr</sub> Test Circuit

Figure 14.  $t_{rr}$  Waveforms and Definitions



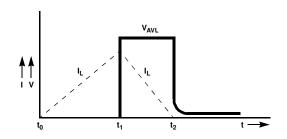


Figure 15. Avalanche Energy Test Circuit

Figure 16. Avalanche Current and Voltage Waveforms

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